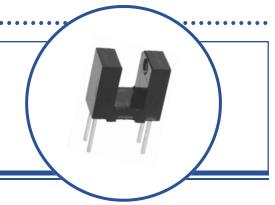
Slotted Optical Switch OPB610, OPB611, OPB620, OPB621



Features:

- Non-contact switching
- · Printed circuit board mounting
- · Enhanced signal to noise ratio
- PIN photodiode sensor for high speed (OPB611, OPB621)
- Lead centers: 0.275" (OPB61) / 0.320" (OPB62)
- Gap: 0.150" (OPB61) / 0.190" (OPB62)



Description:

The OPB610 and OPB620 slotted optical switches consist of an infrared emitting diode and an NPN silicon phototransistor with an enhanced low current roll-off to improve contrast ratio and immunity to background irradiance.

The OPB611, OPB621 slotted optical switch consists of an infrared emitting diode and a PIN photodiode with a polysulfone housing that is opaque to visible light, but transmissive to infrared. The low t_r/t_f of the PIN photodiode is ideal for high-speed operation. The sensitivity to ambient radiation is minimized.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

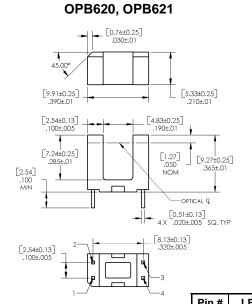
Applications:

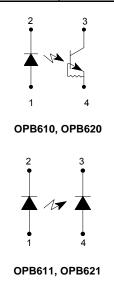
- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- · End of travel sensor
- Door sensor

RoHS

Ordering Information										
Part Number	LED Peak Wavelength	Sensor	Slot Width / Depth	Aperture Emitter / Sensor	Lead Length / Spacing					
OPB610	890 nm	Rbe Transistor	0.150" / 0.240"	0.06" / 0.06"	0.100" / 0.275"					
OPB611		Diode	0.150 / 0.240							
OPB620		Rbe Transistor	0.190" / 0.285"		0.100" / 0.320"					
OPB621		Diode	0.190 / 0.200							

OPB610, OPB611 [0.76±0.25] 45.00 [5.33±0.25] .210±.01 [8.89±0.25] .350±.01 [2.54±0.13] .100±.005 [3.81±0.25] .150±.01 [6.10±0.25] [1.27] .050 NOM -OPTICAL G [0.51±0.13] .020±.005 SQ. TYP [6.99±0.13] .275±.005 [2.54±0.13] .100±.005





Pin# LED Pin# Transistor / Diode Anode 4 Emitter / Anode 2 Cathode Collector / Cathode

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

[MILLIMETERS]

INCHES

DIMENSIONS ARE IN:

Slotted Optical Switch OPB610, OPB611, OPB620, OPB621



Storac	Absolute Maximum Ratings (T _A =25°C unless otherwise noted) Storage and Operating Temperature Range									
	Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] ⁽¹⁾									
Input Diod		1) 110111	ine cas	e 101 5 3	ec. with a	soluering ironj	260° C			
•							50 mA			
	Forward DC Current Peak Forward Current (1 µs pulse width, 300 pps)									
Rever	3 A									
Power	100 mW									
	otodiode (OPB621)						100 1111			
-	Reverse Breakdown Voltage									
	Power Dissipation									
	ototransistor (OPB610, OPB620)						100 mW			
•	Collector-Emitter Voltage									
Emitte	24 V 10 mA									
Collec	30 mA									
Powe	200 mW									
Electrica	al Characteristics (T _A = 25°C unles	s othe	rwise r	noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS				
nput Diod	le (See OP240 for additional information)	<u> </u>			I					
V _F	Forward Voltage OPB610, OPB620 OPB621	- 1.15		1.6 1.45	V	I _F = 10 mA I _F = 10 mA				
I _R	Reverse Current	-	-	100	μA	V _R = 3 V				
Output Ph	ototransistor (OPB610, OPB620) (See	OP505	for add	itional in	formation	n)				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	24	-	-	V	I _C = 100 μA				
BV_{ECO}	Emitter-Collector Breakdown Voltage	0.4	-	-	V	I _{CE} = 100 μA				
I _{CEO}	Collector-Emitter Dark Current	-	-	100	nA	V _{CE} = 5 V				
Output Ph	otodiode (OPB611, OPB621) (See OP9	99 for a	ddition	al inform	nation)					
I _D	Dark Current		-	65	nA	V _R = 30 V, E _E = 0 mW				
$V_{(BR)R}$	Reverse Breakdown Voltage	60	1	_	V	IR = 100 μA, E _E = 0 mW				
V_{F}	Forward Voltage	-	-	1.0	V	I _F = 1 mA, E _E = 0 mW				
Combined										
V_{SAT}	Collector-Emitter Saturation Voltage OPB610, OPB620	-	-	0.4	V	I _F = 5 mA, I _C = 100 μA				
	On-State Collector/Diode Current									

Notes

 $I_{C(ON)}$

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering.

mΑ

μA

90

(2) Derate linearly 1.33 mW/°C above 25 ° C.

OPB610, OPB620

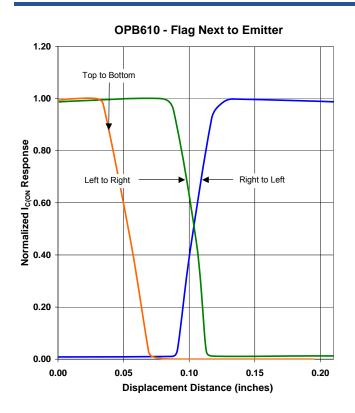
OPB611, OPB621

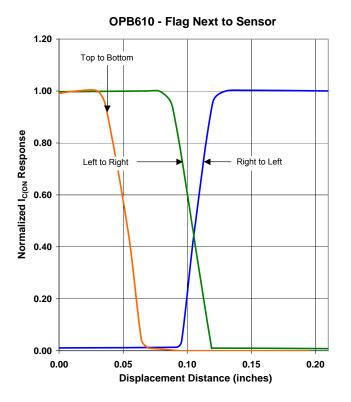
(3) Derate linearly 2.0 mW/°C above 25 ° C.

 $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V (gap unblocked)}$

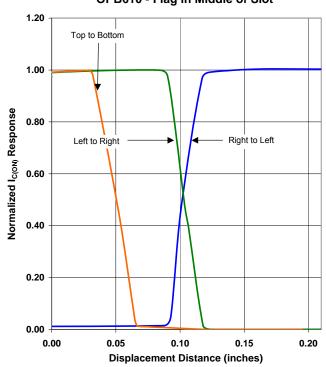
 $V_R = 5 \text{ V}, I_F = 20 \text{ mA (gap unblocked)}$

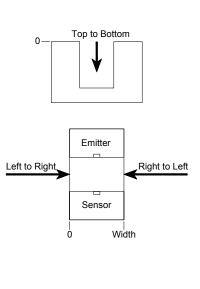






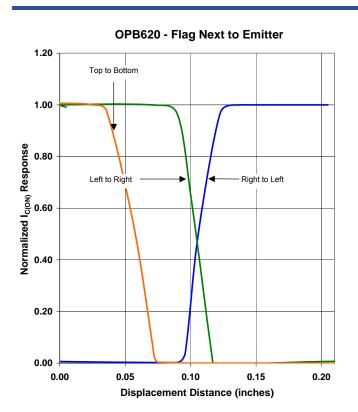
OPB610 - Flag in Middle of Slot

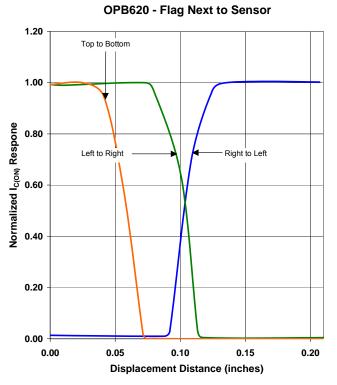




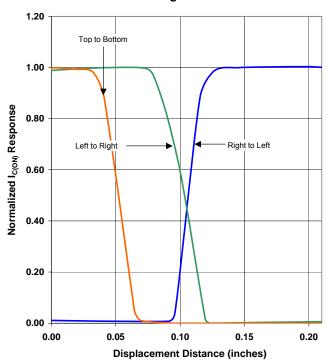
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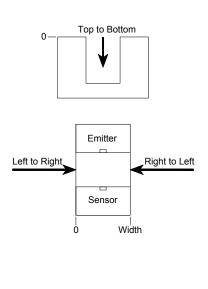






OPB620 - Flag in Middle of Slot





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